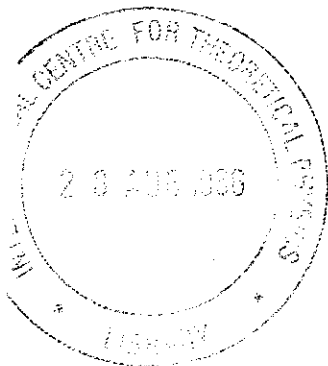




INTERNATIONAL ATOMIC ENERGY AGENCY
UNITED NATIONS EDUCATIONAL, SCIENTIFIC AND CULTURAL ORGANIZATION



INTERNATIONAL CENTRE FOR THEORETICAL PHYSICS
34100 TRIESTE (ITALY) - P.O.B. 588 - MIRAMARE - STRADA COSTIERA 11 - TELEPHONE: 2240-1
CABLE: CENTRATOM - TELEX 400892-1

SMR/178 - 3

Working Party on
PHYSICS OF CONDENSED MATTER AT HIGH PRESSURES
(11 - 29 August 1986)

HIGH PRESSURE TRENDS IN ELECTRONIC STRUCTURE

A. McMAHAN
L-299
Lawrence Livermore National Laboratory
P.O. Box 808
Livermore, CA 94550
U.S.A.

High Pressure Trends in Electronic Structure

Many diverse phenomena including

- metal, semimetal, insulator trans's
- structural phase transitions
- pressure-volume anomalies

Due to simple changes in electronic structure with P

- * $sp \rightarrow d$ transition
- loss covalency
- f-shell delocalization

Often trends with P (fixed Z) $\Leftrightarrow$ Z ($P=0$)

P changes R_{ws}
(Wigner-Seitz)



Z changes ionic
(i.e. core) radius R_i

Talk reviews electron band theory interpretation of expt. to illustrate trends

Brief Review of Electron Band Theory

- The whole story for $T \sim 298\text{ K}$

$$P(V, T) = P(V, 0) + \underbrace{\Delta P_0(V, T)}_{\sim 0} + \underbrace{\Delta P_n(V, T)}_{\Theta(0.01 \text{ mbar})}$$



- $T=0$ band theory (eg. APW, LMTO)

$$\left[-\frac{\hbar^2}{2m} \nabla_i^2 + \sum_{\vec{R}} \frac{-Ze^2}{|\vec{r}-\vec{R}|} + \int d\vec{r}' \frac{\rho(\vec{r}')e^2}{|\vec{r}-\vec{r}'|} + V_{xc}(\rho) \right] \psi_i = \epsilon_i \psi_i$$

self-consistent

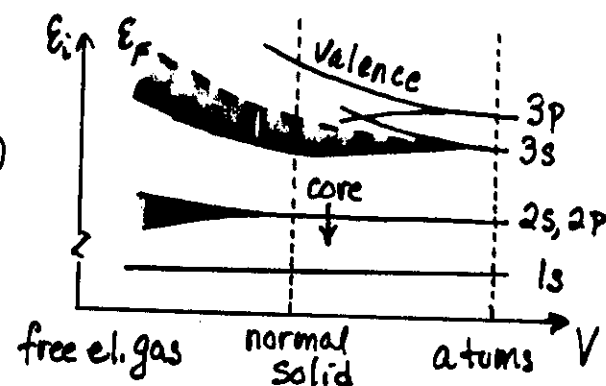
$$E(V, 0) = \sum_i^{\text{occ.}} \epsilon_i - \text{overcounting P.E.} + \sum_{\vec{R} < \vec{R}'} \frac{Z^2 e^2}{|\vec{R}-\vec{R}'|}$$

$$P(V, 0) = -\frac{dE(V, 0)}{dV} = \sum_i^{\text{occ.}} P_i \quad (\text{Lieberman})$$

- atoms $\rightarrow$ free el. gas

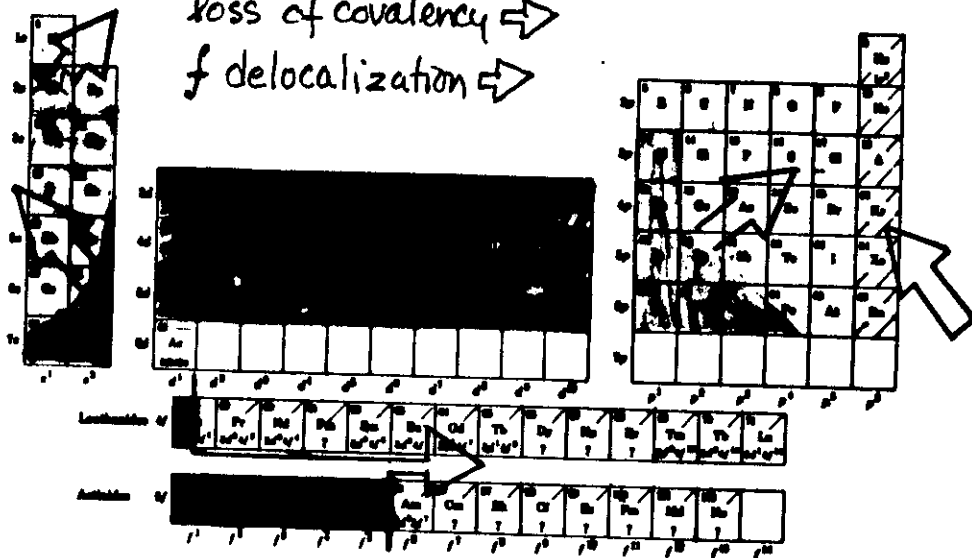
$$K.E. \sim V^{-2/3} \quad (\text{wins out})$$

$$P.E. \sim V^{-1/3}$$



Trends with increasing pressure

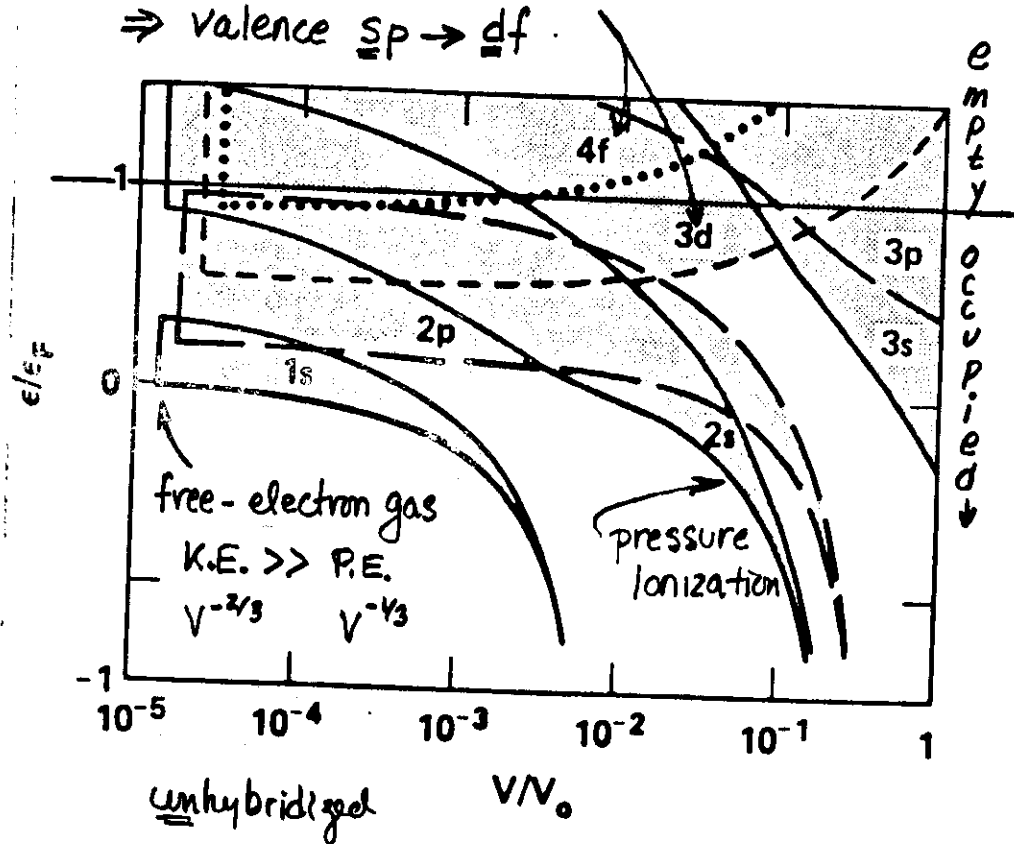
$sp \rightarrow d$ transition $\Rightarrow$
 loss of covalency $\Rightarrow$
 f delocalization $\Rightarrow$



- ☒ filled shell (sp)
- ☐ covalent (sp)
- ☒ simple metal (sp)
- ☒ transition metal (d)
- ☒ rare earth / late actinide (f)
- ☒ early actinide (f)

I. Electronic $s \rightarrow d$ transition ... e.g. Al

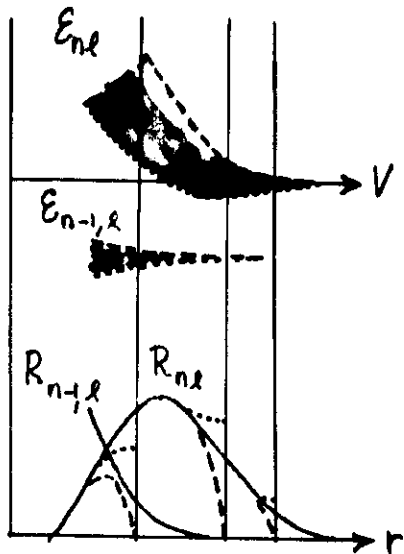
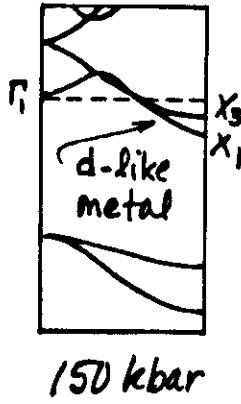
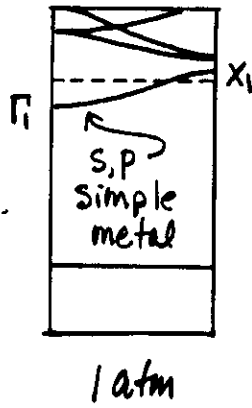
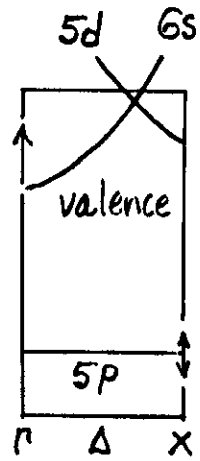
Higher l bands with fewer radial nodes drop relative to other levels
 $\Rightarrow$ valence $\underline{sp} \rightarrow \underline{df}$



Electronic $s \rightarrow d$ transition ... e.g. Cs

5

6



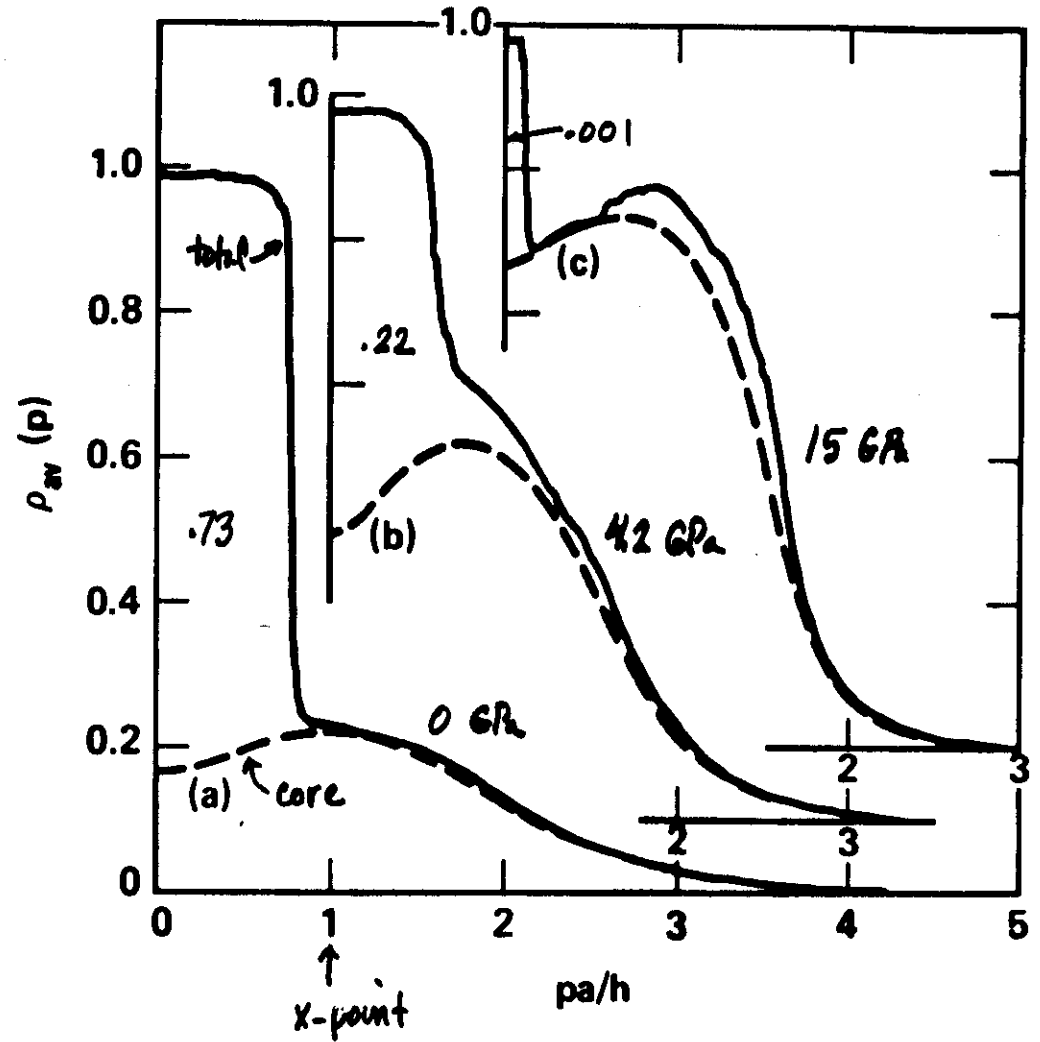
Why?

- KE ($V^{-4/3}$) vs. PE ($V^{-1/3}$)
6s (5 nodes) 5d (2 nodes)
- more localized 5d orbital

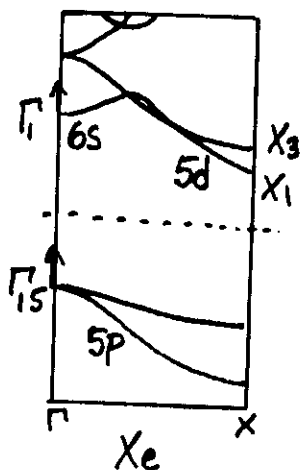
Note

- pressure ionization (5p core)
 $\Leftrightarrow$ elect. trans. ($s \rightarrow d$ val)

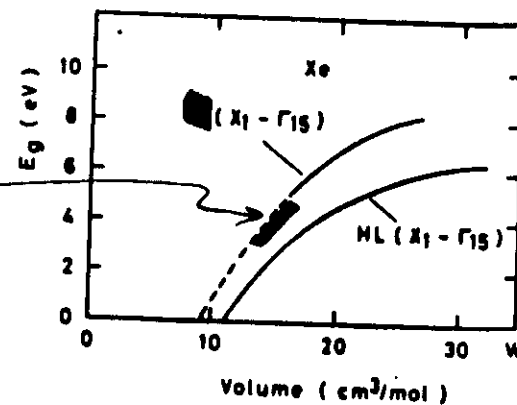
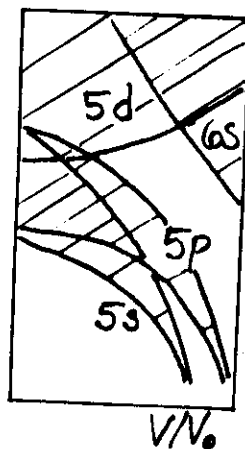
Cs electron momentum density $\bar{j}(p)$



Closed-Shell Metallization



SLATER
EXCH.
CORR.
IS
BEST



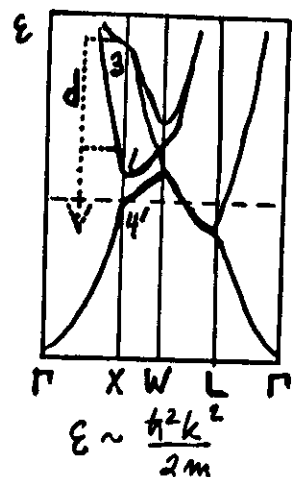
Asuami et. al.

	<i>l</i>	<i>l</i> +1	P_{Th}^{HL}	P_{Th}^S	$P_{expt.}$
He	1s	2p	1/2		
Ne	2p	3d	1,580 ^a		(Mbar)
Ar	3p	3d	6.9		
Kr	4p	4d			
Xe	5p	5d	13 ^b	2 ^b	~2 (extra.) ^c
CsI	"	"	0.58 ^d		1.1 ± 0.1 ^e
BaTe	"	"			0.20 ^f

^a Hama ^b Ross-McM ^c Asuami et. al., Syassen
^d Satpathy et. al. ^e Reichlin et. al. ^f Grzybowski-Rueff

Metal → semimetal → metal transitions

- Divalent, for, nearly-free-el. metal

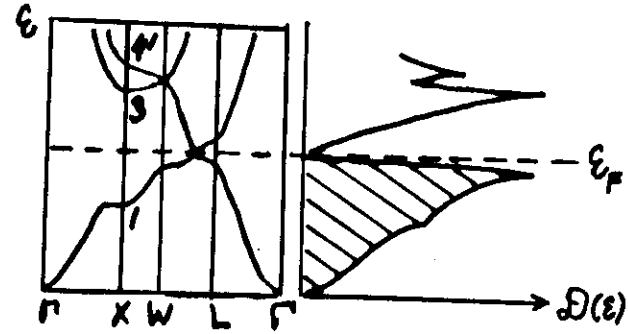


$$\epsilon \sim \frac{\hbar^2 k^2}{2m}$$

- Predictions semimetal range

*Skriver (many earlier, incl. Vasvari et. al., Mickish et. al.)

- d band comes down with P
 ⇒ semimetal range



Mg	24-62 Mbar?
Ca	70-210 kbar*
Sr	3-40* 0-60*
Ba	
La	
Yb	

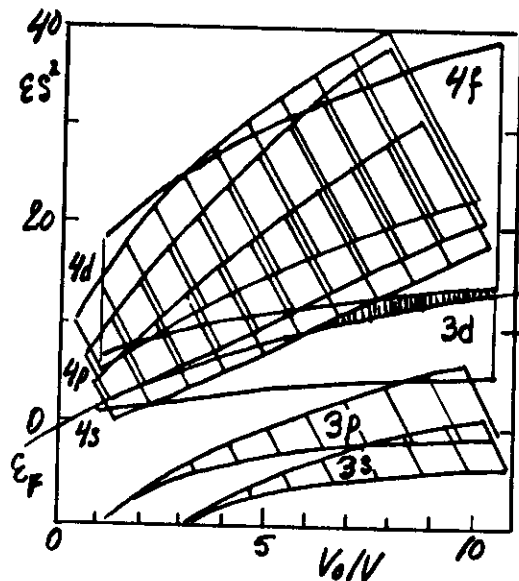
← bcc →

- Resistivity expt. (eg., Ca, Dunn-Bundy)

ρ increas. with P
 $\rho / T < 0$

consistent with semimetal
 they suggest 180 kbar →

Metal-insulator-metal trans. in high P nickel



- 10 3d, 4s valence el's
- gap opens when 3d drops below 4s (34 TPa)
- back to metal when 4f overlaps 3d (51 TPa)

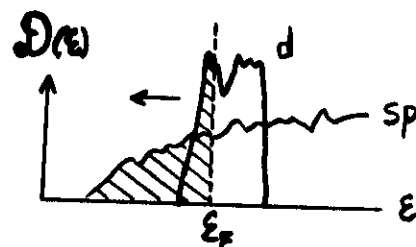
Gandel'man et al.
Mcmahan & Albers

Structural Phase Transitions and sp-d transition

- Seq's of structures with P or Z ← delicate energy diff's

$$E_{bcc} - E_{fcc} \sim \int_0^{\epsilon_F} d\epsilon \epsilon [D_{bcc}(\epsilon) - D_{fcc}(\epsilon)]$$

- But driving force - change in el. structure - clear:

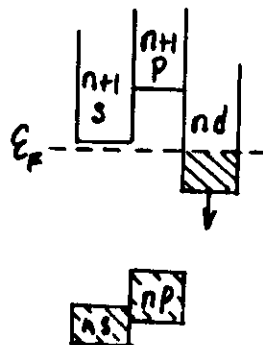


change in relative
sp-d position

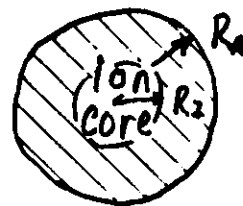
end s-d transition, P (GPa)

	50	260	34,000	
d	K	Ca	Sc	Ni
	Rb	Sr	Y	...
	Cs	Ba	La	Pd
	10	60		Pt

s	Cu	Zn
	Ag	Cd
	Au	Hg



- Due to compression of valence electrons



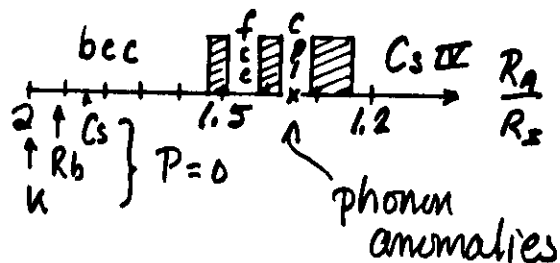
R_A/R_Z decreases
due to P or Z

- $\therefore$ structures $\Leftrightarrow R_A/R_Z$ or N_d (no of d electrons, another measure of sp-d separation).

s-d driven structural sequences

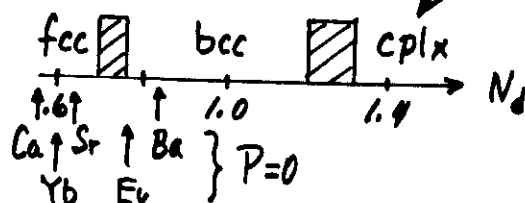
K	Ca	Sc														
Rb	Sr	Y														
Cs	Ba	La	Ce	Pr	Nd	Pm	Sm	Eu	Gd	Tb	Dy	Ho	Er	Tm	Yb	Lu

mono-valent



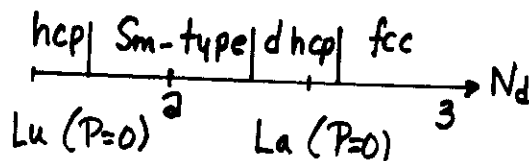
Takemura
- Syassen
Olynik
- Holzappel

divalent



Olynik
- Holzappel
Skriver

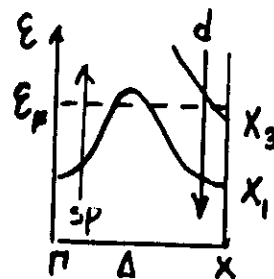
trivalent



Jayaraman
Duthie
- Pettifer

Equation of state & Phonon anomalies

12



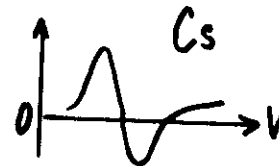
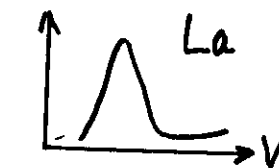
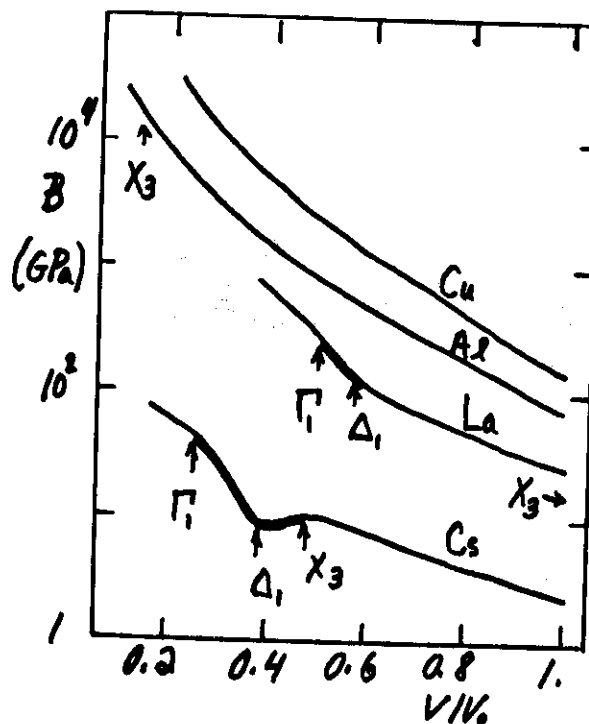
$$P \sim \sum_i^{\infty} \left(-\frac{d\epsilon_i}{dV} \right)$$

$$B = -\frac{dP}{d \ln V}$$

$$\gamma = -\frac{d \ln \omega_D}{d \ln V} \left(k_D \sqrt{\frac{b}{\rho}} \right)^3$$

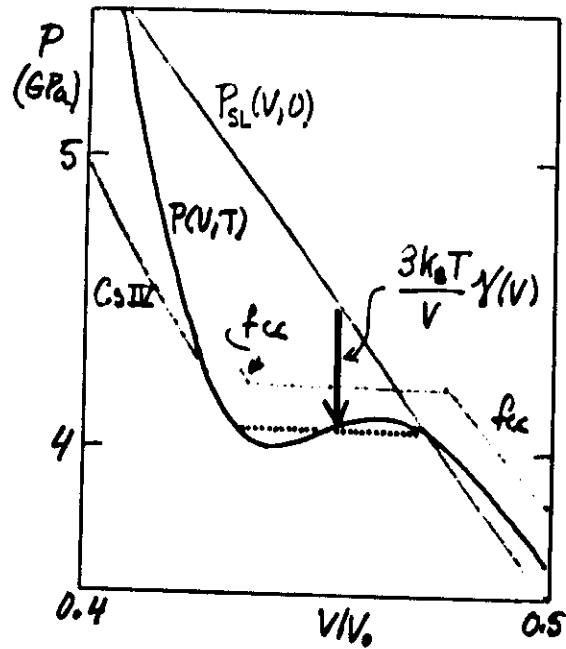
(Slater) Grüneisen γ

$$\gamma \sim -\frac{1}{6} - \frac{1}{2} \frac{d \ln B}{d \ln V}$$



Phonon induced fcc-fcc transition in Cs

$$P(V, 298K) = \underset{\substack{\text{static} \\ \text{lattice}}}{P_{SL}(V, 0)} + \underset{\substack{\text{Phonon}}}{\frac{3k_B T}{V} \gamma(V)}$$

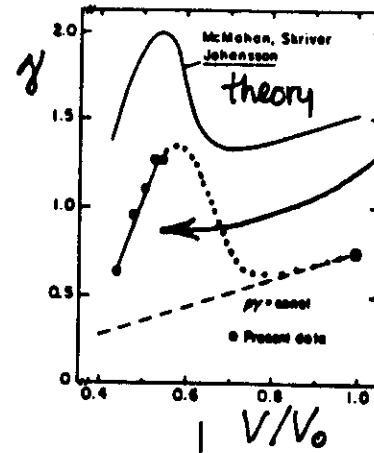


negative $\gamma(V)$
 $\downarrow$
 van der Waals loop in $P(V, 298K)$
 $\parallel$
 1st order fcc $\rightarrow$ fcc transition

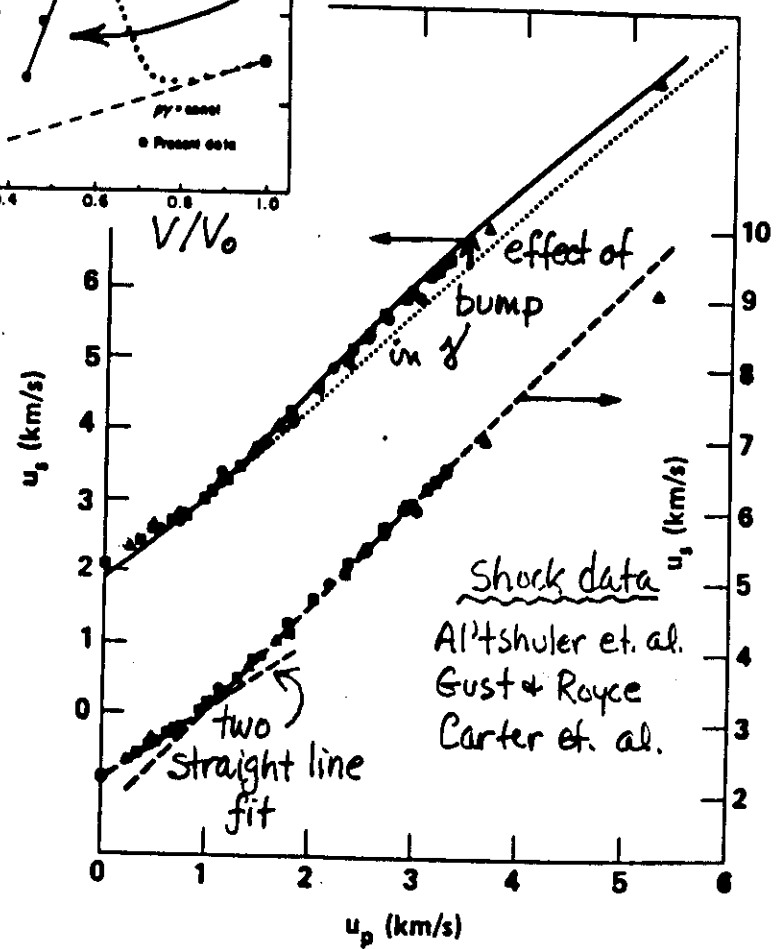
phonon anomalies $\longleftrightarrow$ "complex" regions of alkali, alkaline earth sequences

Boehler - Ross

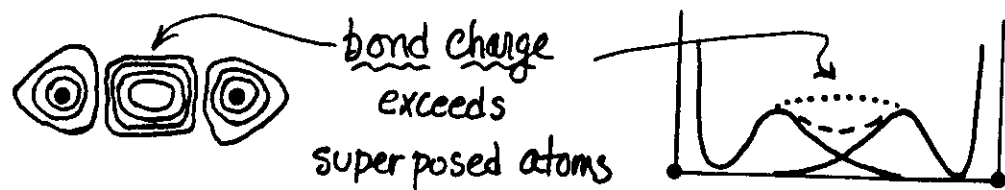
Anomaly in La Shock data



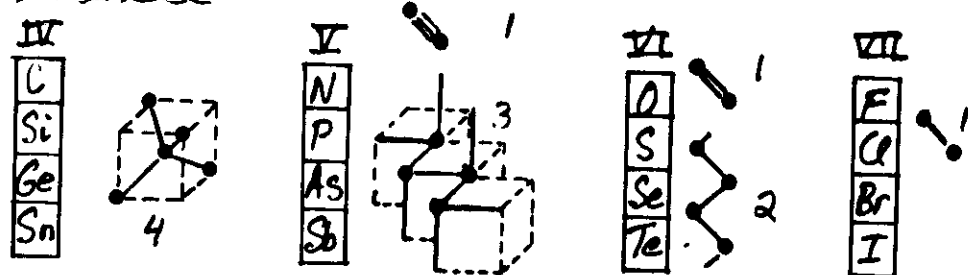
γ measurement (from sound speed)
 Brown, Shaner & Swenson



II. Loss of covalency: bonding (PE) vs. delocalized (KE)



Coordination



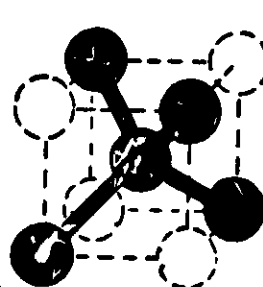
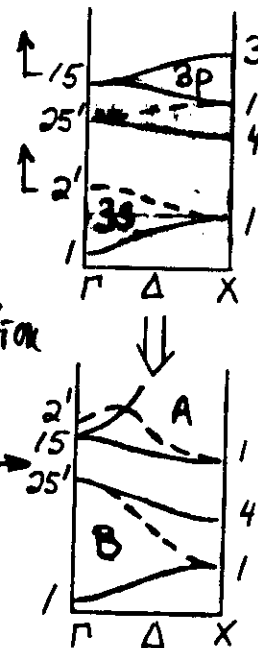
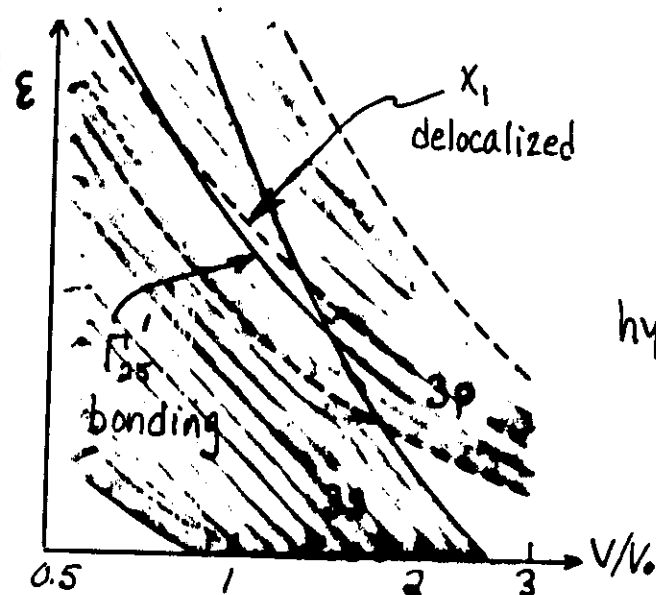
trends

- decreasing bond charge
- tran's to higher coordination $4 \rightarrow 6-12$
- insulator $\rightarrow$ semicand./semimetal $\rightarrow$ metal

why

- advantage localized, bond charge mostly PE (V^{-3})
- KE ($V^{-2/3}$) favors delocalized charge & wins out

Loss of hybridization gap in diamond phase Si



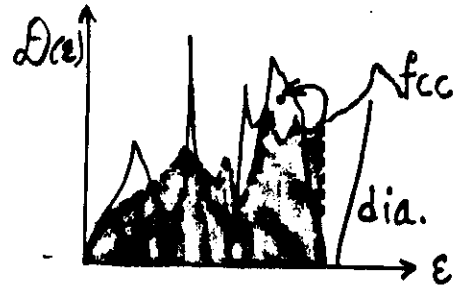
% of 144^2 in*

	●	○
Γ_{25}'	93	7
X_1	51	49

*space filling spheres

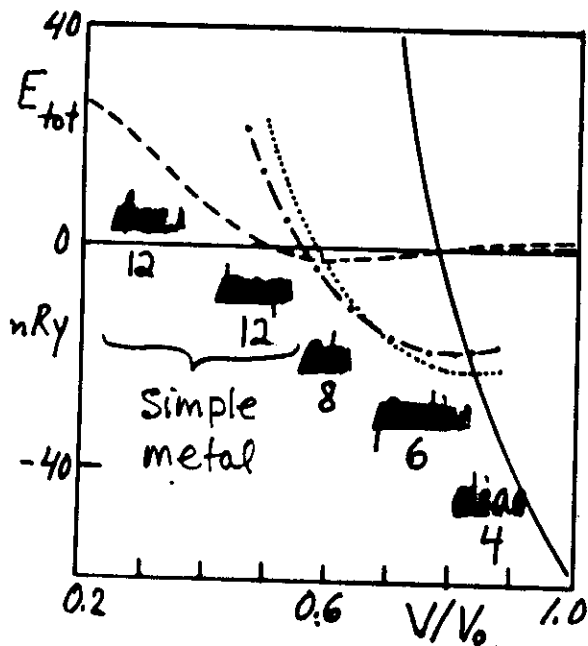
KE favors more delocalized Δ_1 & X_1 . They drop relative to bonding Γ_{25}' ... closing gap.

Even at $V/V_0=1$ fcc Si $\sim$ simple metal ($\Delta E \propto \epsilon^{-1/2}$)



hybridization gap gives
covalent diamond structure
lower E_{tot}

with loss of gap ($V/V_0 \sim 0.78$) diamond str. less competitive



Covalent $\rightarrow$ simple metal
evolution completed by
hcp, coordination 12

sequence observed through
hcp (Clijnk et al,
Hu & Spain)

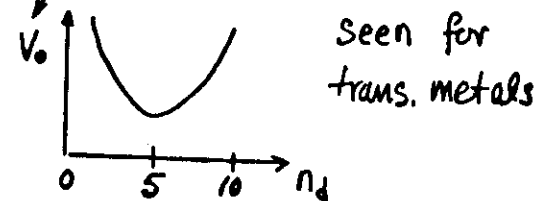
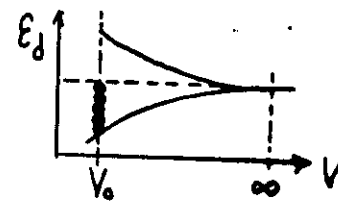
theory: Needs & Martin, Chang
& Cohen, McM & Morant

III. f-shell delocalization



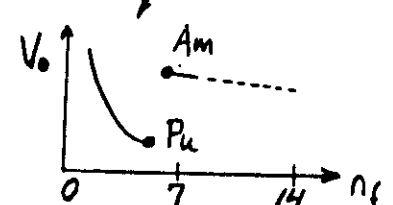
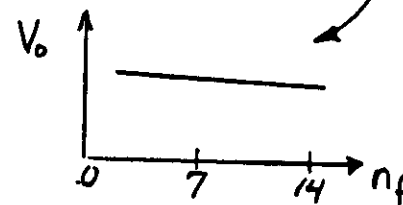
□ parabolic $V_0(n_f)$
Complex structures
■ flat $V_0(n_f)$
rare earth structures

- Simple tight binding $\Rightarrow$ parabolic $V(P=0)$ with no. d el's, n_d



seen for
trans. metals

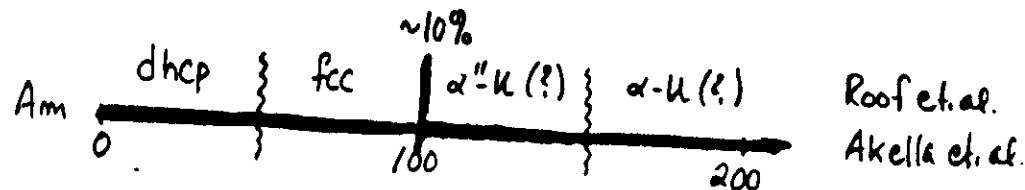
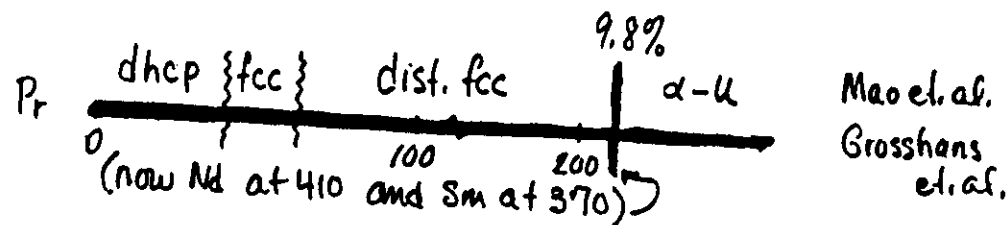
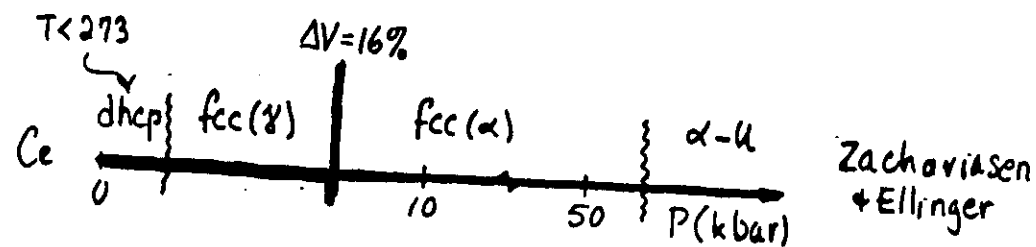
- But for f bands, rare earths (+s) and actinides, see



- As if f's atomic-like, "localized" in RE's & late actinides
" band-like, "delocalized" in early actinides

Localization → delocalization trans. seen under P

19th



Note: Grosshans et al. suggest "localized" RE^{+3} Seq.
is $hep \rightarrow Sm \rightarrow dhcp \rightarrow fcc \rightarrow dist. fcc$ ← Seen Y, La, Pr

